

High Power Density 1 W Laser Diode

* 2 QW-SCH : Quantum Well Separate Confinement Heterostructure

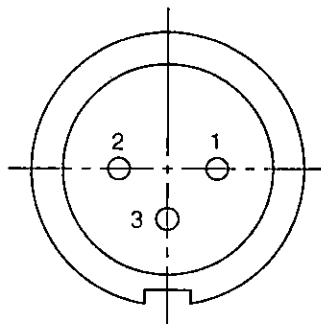
- High power
Recommended optical power output: $P_o=1.0\text{ W}$
- Low operating current: $I_{op}=1.4\text{ A}$ ($P_o=1.0\text{ W}$)

- Solid state laser excitation
- Medical use
- Material processes
- Measurement

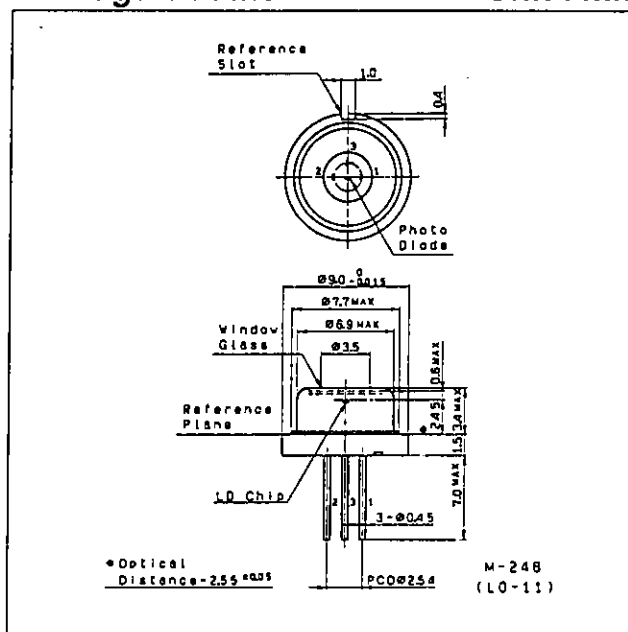
GaAlAs quantum well structure laser diode

●Optical power output	P _o	1.1	W
●Reverse voltage	V _R LD	2	V
	PD	15	V
●Operating temperature (T _c)	T _{opr}	−10 to +30	°C
●Storage temperature	T _{stg}	−40 to +85	°C

No.	Function
1	Laser diode cathode
2	Photo diode anode
3	Common



Unit : mm



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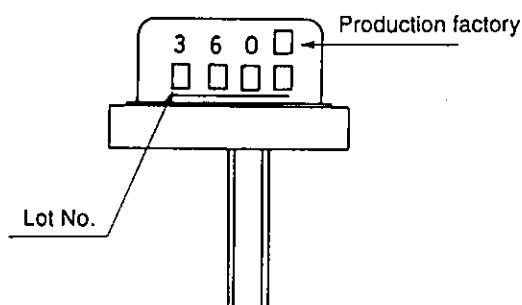
Optical and Electrical Characteristics (T_c=case temperature T_c=25°C)

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Threshold current	I _{th}			0.3	0.5	A
Operating current	I _{op}	P _o =1.0 W		1.4	2.0	A
Operating voltage	V _{op}	P _o =1.0 W		2.1	3.0	V
Wavelength ☆	λ _p	P _o =1.0 W	790		840	nm
Monitor current	I _{mon}	P _o =1.0 W V _R =10 V	0.3	1.5	6.0	mA
Radiation angle (F. W. H. M)	Perpendicular	θ _⊥	20	30	40	degree
	Parallel	θ _∥				degree
Positional accuracy	Position	ΔX, ΔY			±50	μm
	Angle	Δφ _⊥				degree
Differential efficiency	η _D	P _o =1.0 W	0.5	0.9		W/A

☆ Wavelength Classification

Type	Wavelength (nm)
SLD323V-1	795±5
SLD323V-2	810±10
SLD323V-3	830±10
SLD323V-21	798±3
SLD323V-24	807±3
SLD323V-25	810±3

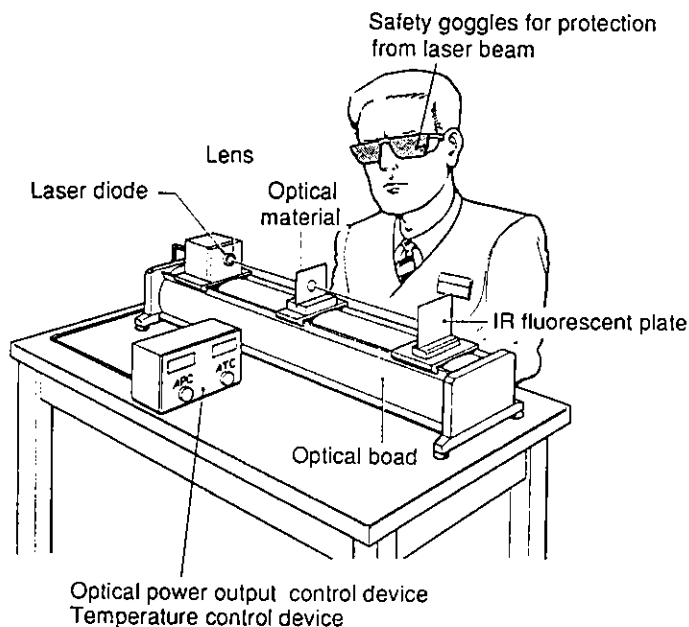
Marking



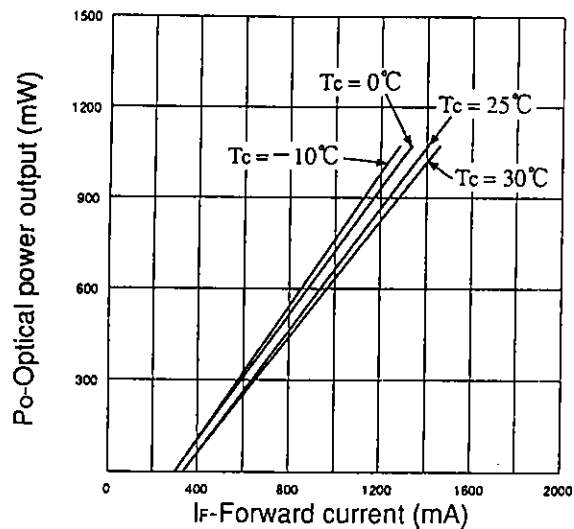
Handling Precautions

Eye protection against laser beams

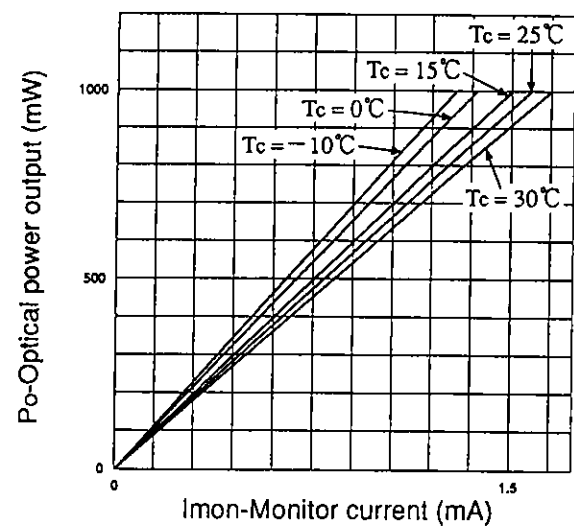
The optical output of laser diodes ranges from several mW to 3 W. However the optical power density of the laser beam at the diode chip reaches 1 MW/cm². Unlike gas lasers, since laser diode beams are divergent, uncollimated laser diode beams are fairly safe at a laser diode. For observing laser beams, ALWAYS use safety goggles that block infrared rays. Usage of IR scopes, IR cameras and fluorescent plates is also recommended for monitoring laser beams safely.



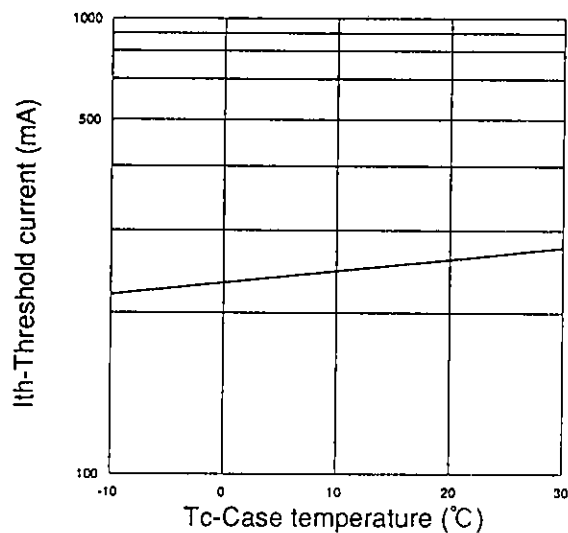
Optical power output vs. Forward current characteristics



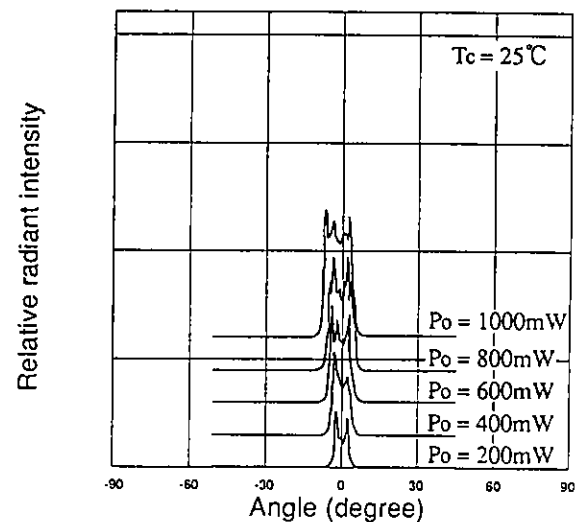
Optical power output vs. Monitor current characteristics



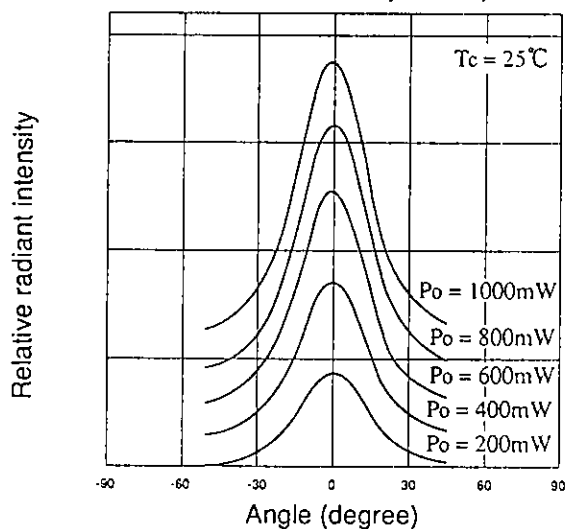
Threshold current vs. Temperature characteristics



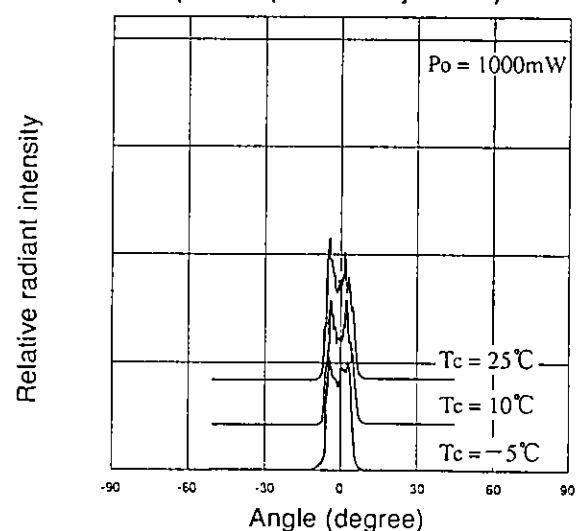
Power dependence of far field pattern (Parallel to junction)



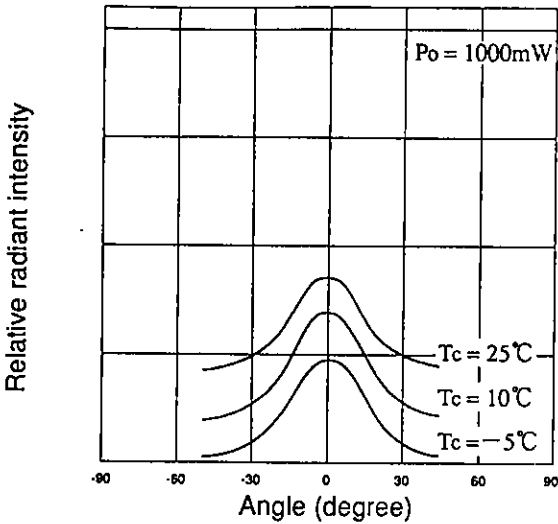
Power dependence of far field pattern (Perpendicular to junction)



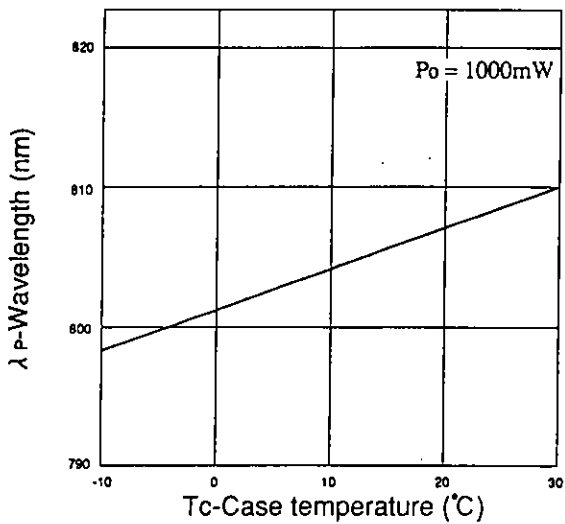
Temperature dependence of far field pattern (Parallel to junction)



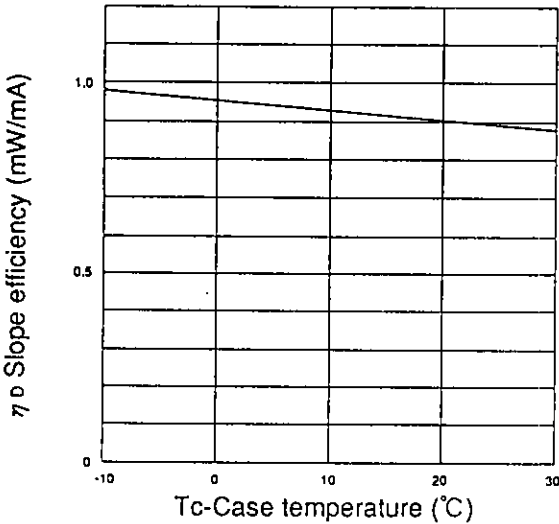
Temperature dependence of far field pattern (Perpendicular to junction)



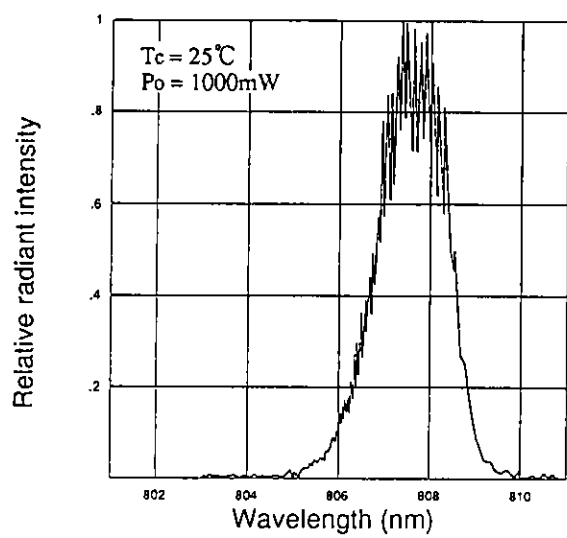
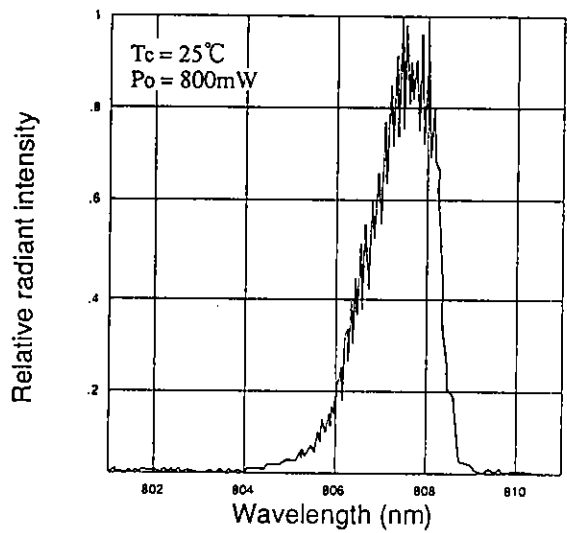
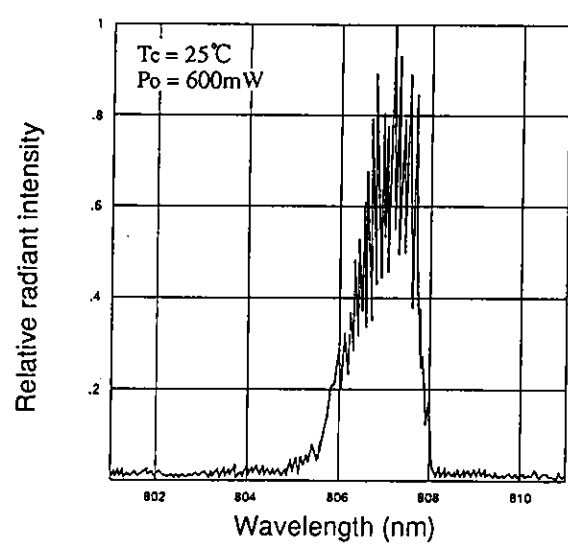
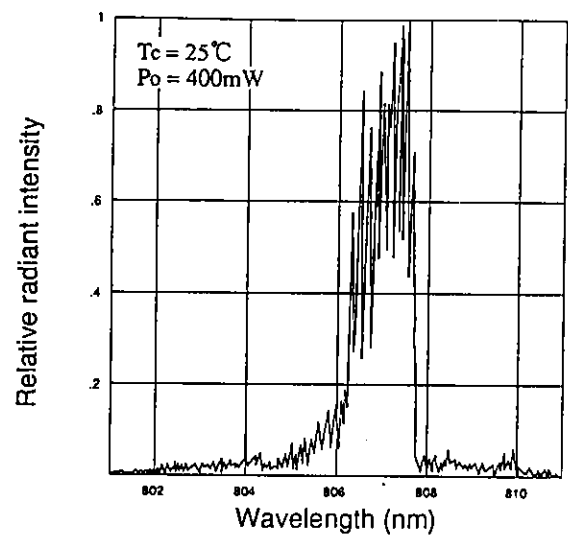
Dependence of wavelength



Slope efficiency vs. Temperature characteristics



Power dependence of spectrum



Temperature dependence of spectrum ($P_o=0.5\text{ W}$)

